## Slave-Boson Three-Band M odel with 0-0 H opping for H igh-T<sub>c</sub> Superconductors

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Slave boson mean-eld approximation is carried out analytically for weakly doped CuO<sub>2</sub> conduction planes, characterized by Cu-O charge transfer energy  $_{pd}$ , Cu-O hopping  $t_0$ , O-O hopping  $t^0$ , and repulsion U<sub>d</sub> between holes on Cu site taken as in nite. At zero doping , nite negative  $t', j^0 j < t_0=2$ , expands the range of stability of the covalent, conducting state on the expense of the insulating state which, however, remains stable at larger  $_{pd}$ . For su ciently large  $_{pd}$  the renorm alized charge transfer energy saturates at  $4j^0 j$  instead of decreasing to zero, as at  $t^0 = 0$  case. In contrast to  $t^0$ , nite suppresses the insulating state nearly symmetrically with respect to the sign of . The regime with charge transfer energy renorm alized close to  $4j^0 j$  ts remarkably well the ARPES spectra of B i2212 and LSCO, and, in the latter case, explains the observed strong doping dependence of the Cu-O hopping.

ARPES measurements of the electron spectra in the high-T  $_{\rm c}$  superconductors [1 {4] have show n that the characteristic band energy scales fall into the range between 0.1 and 1 eV. On the other hand, the high-energy spectroscopies indicate considerably larger characteristic energies, of the order of several eV [5]. This im plies that the renormalization of the electron spectrum in low energy range m easured by ARPES is strong. Recent results on La<sub>2 x</sub>Sr<sub>x</sub>CuO<sub>4</sub> (LSCO) [1] have shown in addition that the shape of the Ferm i surface varies strongly with doping, indicating again strong renorm alization of band param eters. Further argum ent in favor of the strong renormalization comes from the approximate electronhole sym m etry of the phase diagram of the high-T c superconductors [5]. If the couplings were weak, band renorm alization sm all, the approxim ate electron-hole sym m etry would occur with respect to the (optim al) doping  $_{\rm c}$ , necessary to bring the Ferm i level to the logarithm ic van Hove singularity. This would be accompanied by the activation of the Um klapp scattering, i.e. tendency tow ards M ott localization. Thus far such tendency has not been observed and the approxim ate symmetry occurs with respect to = 0 rather than with respect to <sub>c</sub>. This rules out weak coupling and raises the question whether interm ediate [6] to strong [7] coupling can account for such behavior.

It is usually assumed that the largest coupling is the local hole-hole interaction  $U_d$  on the Cu-site of the conducting CuO<sub>2</sub> planes. The interaction problem is offen treated within the Emery model [8] which describes the three-site structure of the CuO<sub>2</sub> plane by copper and oxygen site energies "<sub>d</sub> and "<sub>p</sub> respectively, the Cu-O hopping t<sub>0</sub> and the O-O hopping t<sub>0</sub>, the single-particle parameters in addition to U<sub>d</sub>. The strong renorm alization of the band structure characterized by "<sub>d</sub>, "<sub>p</sub>, t<sub>0</sub> and t<sub>0</sub><sup>0</sup> is thus expected only when the number of holes on the Cu-site is close to unity, because only then large U<sub>d</sub> is elective. In the opposite case, when the holes tend to reside on

oxygen sites, the renorm alization should decrease. Bearing this in mind, the limit of large  $U_d$  is discussed here, taking  $U_d$  larger than  $p_d = "p = "d, t_0, t'_0$ . The limit of in nite  $U_d$  is, as usual, treated within mean-eld slave boson approximation [7,9], neglecting the AF and SC effects. The latter occur [5] on the energy scales of the 0.01 eV, an order of magnitude below the band energy scales of interest here.

P reviously, sim ilar slave boson calculations were carried out analytically for the  $t_0$ ,  $t_0^0$  1d (CuO) analog of the 2d ( $CuO_2$ ) case [9], and, for the latter, num erically for som e particular choices of the bare param eters [9{11]. The 2d three-band structure is considerably richer than its 1d two-band counterpart, therefore, sim ilar holds for the corresponding m ean-eld slave boson theory. In particular, the 2d case is sensitive to the sign of  $t_0^0$ . Two bands may anticross, as in the 1d case, but in 2d case, band-touching is also possible [11,12]. Above all, in contrast to 1d m odel, the parameter  $t_0^0$  removes in 2d case Ferm i energy of the half-lled band from the van Hove singularity, i.e. introduces a nite doping c required to bring it back [12]. The question whether the electronhole symmetry occurs for = 0 or <sub>c</sub> should therefore be discussed at nite  $t'_0$ .

The slave boson procedure [7] am ounts to searching the ground state band energy E<sub>0</sub> at a given number of holes 1+, subjected to the restriction that the number of holes  $n_d$  on the Cu-site is smaller than 1, as required by large  $U_d$ . In the mean-eld approximation  $E_0$  is the energy of the free holes with the renormalized band parameters ;t;t<sup>0</sup>, chosen to full lt the requirement  $l_d i < 1$ , which becomes [7]

$$m_{d}i + t^2 = t_0^2 = 1; \ m_di = \frac{\Theta E_0}{\Theta}$$
: (1)

The m inim ization of E $_0$  with respect to the remaining parameter t, gives the second slave boson equation

$$m_{\rm B} i = 2 \frac{t(_{\rm pd})}{t_0^2}; \ m_{\rm B} i = \frac{@E_0}{@t};$$
 (2)

denoting renorm alized bond charge on the Cu-O bond.

The solution of the coupled integro-di erential equations (1) and (2) gives and t as functions of  $_{pd}$ ,  $t_0$ , t' and (remembering that  $t_0^0 = t^0$ ). The present slave boson calculation is carried out for arbitrary  $_{pd}$  and  $t_0$ , assuming  $2t_0^0 j < t_0$  and j j << 1. The assum ption  $2t_0^0 j < t_0$  is in the spirit of the Emery model [8], but the opposite lim it will nevertheless be brie y commented upon. On the other hand, the results obtained here for j j << 1 do not cover all the physically achieved doping, but rather indicate the tendencies associated with nite

It is possible to transform [13] the integro-di erential equations (1) and (2) to the coupled algebraic equations for all interesting regim es of param eters by calculating  $E_0$  (;t;t<sup>0</sup>; ) analytically and then  $m_di$  and  $m_B i$  from Eqs. (1) and (2). Leaving the details of the calculation for the extended publication [13], the nalresults will be discussed here.

These results are best understood starting from the  $t^0 = 0$  situation. "<sub>p</sub>, which does not renorm alize, is chosen for the energy origin, "<sub>p</sub> = 0.0 nly one band, "<sup>0</sup><sub>L</sub> (k), out of three is occupied for 1,

$$\mathbf{T}_{L}^{0}(\mathbf{k}) = \frac{1}{2} \left( \begin{array}{c} 0 \\ 0 \end{array} + \frac{q}{2} \frac{2}{0} + 16t^{2}f_{1} \right);$$
$$f_{1} = \sin^{2}\frac{k_{x}}{2} + \sin^{2}\frac{k_{y}}{2}; \qquad (3)$$

setting  $(t^0 = 0) = 0$ : U sing  $\prod_{L}^{0} (k)$  to calculate  $E_0$ , leads to the solution of the t'= 0 slave boson equations (1) and (2) for arbitrary  $p_d$  and  $t_0$  (taken positive without loss of generality). The behavior of t for = 0is fairly simple:  $t=t_0 = 0$ , starting from large  $p_d$  to  $\prod_{pd}^{cr} = 4:7t_0$ , where the angular point in  $t=t_0$  occurs. For  $p_d$  close below  $\prod_{pd}^{cr} t$  is given by a Landau-like expression t  $\prod_{pd}^{cr} = 1:15t_0 \prod_{pd}^{cr} 0$ , which describes Brinkm an-Rice (BR) phase transition from the insulating t = 0 to the conducting phase. The overall behavior can be obtained by expanding Eq.(3) in terms of  $t^2 = \frac{2}{0}$ including the term softhe order of t<sup>4</sup> close below  $\prod_{pd}^{cr} [7]$ .

The corresponding behavior of  $_{0}(_{pd})$  ism ore in portant for further discussion.  $_{0}$  has a single, maximum (angular at = 0) at  $_{pd} = _{pd}^{cr}$ , where it reaches the value  $_{0} = _{pd}^{cr}=2$ . For  $_{pd}$  well below  $_{pd}^{cr}$  the regime t > j  $_{0}$  j is reached. In didecreases, according to Eq.(1) and so do both renorm alisation of to t and of  $_{pd}$  to  $_{0}$ . Before approaching asymptotically  $_{pd}$  for the large negative  $_{pd}=t_{0}$ ,  $_{0}$  crosses zero [10] at  $_{pd}=t_{0}$  1.5: standard covalent situation  $_{pd}$  to renorm alizes to the extrem e  $_{0}$  0 covalent limit. For >  $_{pd}^{cr}$ , ( $_{pd}$ ) decreases fast towards the asymptotic regime valid for large  $_{pd}$ , when =  $4.7t_{0}^{2} = _{pd}$  tends to zero (similarly to the site energy of the t-J m odel [14]).

Turning next to nite t', in the limit where  $2t^0 j < t_0$ , it is to be noted that under such condition (m ore precisely for  $4t^0 j < {cr \\ pd} = 2 = 2.4t_0$ ),  $4t^0 j$  intersects  $_0 (_{pd})$ at  ${}_{pd}^0 > {}_{pd}^{cr}$ . When  $t^0 j$  to,  ${}_{pd}^0 = 4.7t_0^2 = t^0 j$ . For  $_{pd} < {}_{pd}^{o}$ ,  $4t^0 j$  is smaller than  $_0$  and/or t obtained from t'= 0 solution, and a perturbative treatment of t<sup>0</sup> is possible. For  $_{pd} > {}_{pd}^0$ ,  $4t^0 j > {}_0$  and full treatment oft' is required.

The perturbative corrections due to t' in the regime  $t > _0$  at  $_{pd}$  wellbelow 4.7t<sub>0</sub>, are not of particular interest because only of the quantitative nature. The attention will be therefore focused here on the smallt regime at  $_{pd}$  close below or above 4.7t<sub>0</sub>. For this purpose a perturbative calculation can be carried out in terms of smallt, using (with " $_p = 0$ )

$$\mathbf{"}_{\rm L}(\mathbf{k}) = 4t^2 \frac{f_1}{2} \frac{8t_2}{16t^2} + 0 \ (t^4);$$
$$f_1 = \sin^2 \frac{k_x}{2} \sin^2 \frac{k_y}{2}: \qquad (4)$$

This expansion, valid at 0 for 0 < t < 4fj and arbitrary sign of  $t^0$ , reduces at t'=0 to the spectrum used in obtaining the BR transition, i.e. it is appropriate for following the evolution with t' of the smallt slave boson solution.

In the sst step Eq.(4) is used in the range  $4:7t_0 < p_d < 0_{pd}^0$ , where it can be expanded further in terms of  $0 < t_0^0 \neq 0$ . The following results are obtained retaining the terms linear in t' and quadratic and quartric in t.

The corresponding analytical calculation of the position of the Ferm i level "<sub>F</sub> has been carried out earlier [12], by system atical linearization with respect to t'. The shift of the "<sub>F</sub> from the van Hove singularity at  $_0$  ("<sub>vH</sub> "<sub>F</sub>) =  $2t_0^2 x_F$  turned out to be

$$x_{\rm F} \ln \frac{1}{x_{\rm F}} = \frac{8^{-2} (c_{\rm C})}{1 + 8^{-2} c_{\rm C}}$$
(5)

where  $_{\rm c}=32^{0}_{-}=^2$   $_0$  stands for the critical doping required to bring the Ferm i level back to the van H ove singularity. Experim entally, this doping is positive i.e. signt^0= sign . The linearization procedure can be generalized to the calculation of E\_0 ( ;t;t^0; ), and then, straightforwardly, to the solution of the slave boson equations (1) and (2). Here, for brevity, sm all terms in E\_0, linear in  $x_{\rm F}$ , discussed in Ref. [13],will be om itted in the description of this solution.

The BR transition is shifted to the new position  $_{pd}^{cr} = 4.7t_0 + 3.5 _{c}$ , with  $_c = 13.6t^0 = t_0$ , but it is not suppressed by t'. This important result can be traced back to the outstanding feature of the expansion of Eq.(4) in terms of  $t^0=$ , generating the term  $t^2t^0=$ <sup>2</sup>. The above term vanishes with t, making the theory all along convergent

with respect to  $t^0=$ , as exemplied by Eq.(5), where x  $_F$  is nite and small independently on t.

 $_{\rm cr}$ , the value of in the angular point, is equal to the  $_{\rm pd}^{\rm cr}$ =2, i.e. for  $_{\rm c}$  > 0 it is slightly increased with respect to the t<sup>0</sup> = 0 value, and remains above  $_{\rm 0}$  = (t <sup>0</sup> = 0) in the whole range of convergence of this approach,  $_{\rm pd}^{\rm cr} < _{\rm pd} < _{\rm pd}^{\rm 0}$ .

These results can be extended to nite > 0. In contrast to  $t^0$ , i.e. to  $_c$ , nite suppresses the BR transition, turning it into crossover, in spite of Eq.(5), which suggests analogous roles of  $_c$  and . In the vicinity of  $_{pd}^{cr}$ , the angular behavior of is essentially modiled by nite . For example, the value of at  $_{pd}^{cr} = 4.7t_0 + 3.5_c$  is

$$\frac{cr}{pd}_{2} = 0.8 (1 + 0.2 c)^{1=3}$$
(6)

and correspondingly

$$t^{2} = t_{0}^{2} = 0.63(1 \quad 0.2_{c})^{2=3};$$
(7)

up to the leading orders in  $\quad$  and  $_{\rm c}$ .

Finally we turn to the range  $_{pd} > _{pd}^{0}$ , where the stability of the t = 0 solution is to be discussed using Eq.(4) non-expanded in terms of t', but dropping out 0 (t<sup>4</sup>) term. The main contribution to the cohesive energy E<sub>0</sub> is weakly dependent on "<sub>F</sub> (i.e. <sub>c</sub>) and strongly dependent on lower cut-o, which is <sup>e</sup> =  $4 \pm ^{0}$  j according to Eq.(4), i.e. <sub>c</sub>. (Note in this respect that the "<sub>F</sub> dependency of E<sub>0</sub> was not very in portant even in the vicinity of the BR transition, Eqs.(6) and (7).) Expanding then Eq.(4) around k = (; ) point, one nds in mediately that E<sub>0</sub> is logarithm ic in t<sup>2</sup>=t<sup>0</sup>e, which, through slave boson equations, leads for pd  $_{pd}^{0}$  at = 0 to

$$e = 4 \pm {}^{0} j 2 \pm {}^{0} j \frac{j t^{0} j d}{4 c t^{2}};$$
 (8)

where c is a numerical factor. Eq.(8) shows that the asymptotic behavior of which at  $t^0 = 0$  vanishes as

 $_{0}$   $f_{e}^{=}$  pd, undergoes an essential modi cation to the exponential behavior, with the saturation at = j4t <sup>0</sup>j. A linear the derivation of the result (8) does not suggest that this result is independent of the dimension, the sim – ilar behavior was obtained [9] at = 0 in 1d. Moreover, it is easy to see that nite > 0 leads to t as before. However, the convergence of this result is reduced to t < e, which is itself (exponentially) sm all according to Eq.(8). The regime t e is quickly reached with doping and it is clear that, from the slave boson point of view, the lim it t e is physically achievable.

The corresponding ts of the ARPES data for the Ferm i surfaces of LSCO at di erent doping are shown in Fig.1. These ts also require sign = signt<sup>0</sup> and determ ine two parameters e.g. =t<sup>0</sup> and t=t<sup>0</sup> as functions of .W hile  $4j^0j$  is alm ost independent on doping, t increases quickly with doping. For the underdoped regime

(small doping) the behavior of t can be approximated by , corresponding to the heavy-ferm ion lim it, as suggested by here-presented m ean-eld slave boson theory. However, for larger doping, appreciable values of t are reached, leading the system to the essentially covalent behavior. Finally, for overdoped regime, t and seem to saturate, requiring further theoretical investigation, in particular because the 1d theory [9] suggests otherwise. Here, the calculus becom es quite com plicated since the perturbative treatment of t is no longer possible, and the exact hole spectra are required. Fig.2a shows the conducting band tofBi2Sr2CaCu2O8 (Bi2212), which xes the absolute value of t in addition to the relative values obtained from the Fermi surface ts. t turns out to be of the order of 0.1eV, alm ost an order of m agnitude less than  $t_0$ , again in agreem ent with the present slave boson analysis.

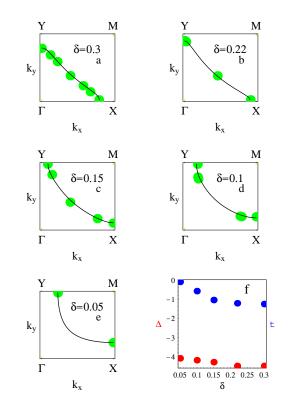


FIG.1. (a-e) Experim entally measured Ferm i surfaces for LSCO [1] (green dots) and the three band model ts (solid). (f) tting parameters in units of  $t^0$  with e small

Equally good ts (c.f. Fig.2b) were however obtained earlier [12] assuming  $j j < 4 \pm 0 j$  rather than  $j^{e}j < 4 \pm 0 j$ . Since it was shown here that the latter is the solution of the 0 slave boson theory when  $2 \pm j < t_0$ , the former can only occur at 0, if  $2 \pm j > t_0$ . While the behavior of e given by Eq.(8) can be visualized, assum ing for the moment t = 0, as the avoided crossing of the dispersionless (t=0) copper level and the pure oxygen band with the energy  $4t_j^2$  at k = (;) point, the  $\lim \pm j \le 4 \pm 0$  jm eans that the Cu level has entered the oxygen band. The holes on Cu site are then necessarily transferred to the oxygen sites, i.e.  $m_d i < 1$ . For n = 1 + , with0, Eq.(1) then requires nite t, i.e. the solution t= 0 is unstable for  $2t^0$  j > t<sub>0</sub>. (For nite t, copper band undergoes anticrossing (sign t' = -sign), rather than touching (sign t' = sign ) with the oxygen band. [11,12]) W ith  $hn_d i < 1$ , the renorm alization becom es sm all, analogously to the case of sm all and neg-<sub>pd</sub> are not expected ative <sub>pd</sub> at t'= 0.t t<sub>e</sub> and to depend much on doping . The appreciable experimental dependence of t on small [1] is therefore an indication in favor of the strongly renorm alized  $2t^0 < t_0$ solution.

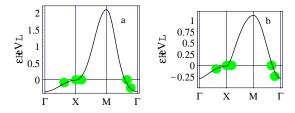


FIG .2. B and - ts for the conducting band of B i2212 of [2], (a) e sm all, (b) sm all

Let us nally point out that  $2t^0 j < t_0$  solution, strongly dependent on doping, is approximately symmetric with respect to the electron ( < 0) or hole doping ( > 0). As the latter was discussed above, leading in particular to t=t<sub>0</sub> for su ciently large  $pd > 4:7t_0$ < 0 will be brie y mentioned here. Since the case n = 1 +, Eq.(1) m eans that t hndi đ , i.e., roughly speaking, t behaves as j j irrespectively of the sign of t = 0 line of the slave boson theory, obtained for the half-lled = 0 Cu-based band, is the singular line of the phase diagram, not only at t'=0, but also for  $t^0~{\mbox{\scriptsize f}}~0$  , as shown here. In the properties depending on the details of the band structure close to the Ferm i surface, the simplest of which is perhaps the Hall constant, the symmetry is broken when a nite t'is taken into account. The corresponding asymmetry is the largest in the small  $t^0 = \lim it of Eq.(5)$ , when > 0 m eans doping towards and < 0 away from the vH singularity, whereas in the opposite  $\lim it of Eq.(8)$ , the Ferm i level at = 0 is so far from the vH singularity, that the variation of the topology of the Ferm i surface with doping becomes small. Overall, the asymmetry is much smaller than in the weak coupling lim it.

In conclusion, the present work shows that the band

structure of the high-T<sub>c</sub> superconductors can be understood in term sofp-d bands in the CuO<sub>2</sub> plane, renorm alized by strong interaction on the Cu-site. A coording to the low energy ARPES data, the bare band param eters, m easured by high energy spectroscopy, are renorm alized by an order of m agnitude. M ore profound understanding of the energy scales, of the order of 0.1 eV, i.e. the understanding of the approxim ate ground state on these energy scales, represents an appropriate prerequisite for consideration of the sym m etry breaking, associated with AF and SC, on the energy scales of 0.01 eV.

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